Triacs

df.dzsc.com

Silicon Bidirectional 40 Amperes RMS Triode Thyristors

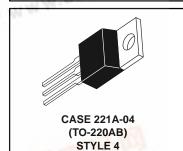
. . . designed primarily for full-wave ac control applications such as lighting systems, heater controls, motor controls and power supplies.

- Blocking Voltage to 800 Volts
- All Diffused and Glass-Passivated Junctions for Parameter Uniformity and Stability
- Gate Triggering Guaranteed in Three Modes (MAC224 Series) or Four Modes (MAC224A Series)

MAC224 Series MAC224A Series

TRIACs 40 AMPERES RMS 200 thru 800 VOLTS





MAXIMUM RATINGS (T_{.J} = 25°C unless otherwise noted.)

Rating	Symbol	Value	Unit	
Peak Repetitive Off-State Voltage(1) (T _J = -40 to 125°C, 1/2 Sine Wave 50 to 60 Hz, Gate Open)	VDRM		Volts	
MAC224-4, MAC224A4 MAC224-6, MAC224A6 MAC224-8, MAC224A8 MAC224-10, MAC224A10		200 400 600 800		
On-State RMS Current (T _C = 75°C)(2) (Full Cycle Sine Wave 50 to 60 Hz)	I _{T(RMS)}	40	Amps	
Peak Non-repetitive Surge Current (One Full Cycle, 60 Hz, T _J = 125°C)	ITSM	350	Amps	
Circuit Fusing (t = 8.3 ms)	l ² t	500	A ² s	
Peak Gate Current (t ≤ 2 μs)	I _{GM}	±2	Amps	
Peak Gate Voltage (t ≤ 2 μs)	V _{GM}	±10	Volts	
Peak Gate Power (t ≤ 2 μs)	PGM	20	Watts	
Average Gate Power ($T_C = 75^{\circ}C$, $t \le 8.3 \text{ ms}$)	P _{G(AV)}	0.5	Watts	
Operating Junction Temperature Range	TJ	-40 to 125	°C	
Storage Temperature Range	T _{stg}	-40 to 150	°C	
Mounting Torque	_	8	in. lb.	

1. V_{DRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source (cont such that the voltage ratings of the devices are exceeded.

This device is rated for use in applications subject to high surge conditions. Care must be taken to insure proper heat sinking when the device used at high sustained currents. (See Figure 1 for maximum case temperatures.)

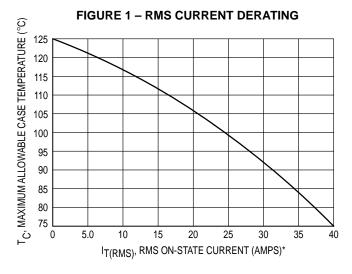
MAC224 Series MAC224A Series

THERMAL CHARACTERISTICS

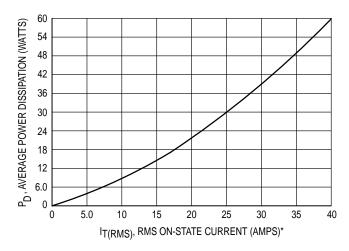
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	1	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	60	°C/W

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ and either polarity of MT2 to MT1 voltage unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Blocking Current (Rated V_{DRM} , Gate Open) $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	IDRM	_	=	10 2	μA mA
Peak On-State Voltage (I _{TM} = 56 A Peak, Pulse Width \leq 2 ms, Duty Cycle \leq 2%)	VTM	_	1.4	1.85	Volts
Gate Trigger Current (Continuous dc) $ (V_D = 12 \text{ V}, \text{ R}_L = 100 \Omega) \\ \text{MT2(+)}, \text{ G(+)}; \text{MT2(+)}, \text{ G(-)}; \text{MT2(+)}, \text{ G(-)} \\ \text{MT2(-)}, \text{ G(+) "A" SUFFIX ONLY} $	lGT		25 40	50 75	mA
Gate Trigger Voltage (Continuous dc) $ (V_D = 12 \text{ V}, \text{ R}_L = 100 \Omega) \\ \text{MT2(+)}, \text{ G(+); MT2(-), G(-); MT(+), G(-)} \\ \text{MT2(-), G(+) "A" SUFFIX ONLY} $	VGT		1.1 1.3	2 2.5	Volts
Gate Non-Trigger Voltage $(V_D = Rated\ V_{DRM},\ T_J = 125^{\circ}C,\ R_L = 10\ k)$ $MT2(+),\ G(+);\ MT2(-),\ G(-);\ MT(+),\ G(-)$ $MT2(-),\ G(+)$	V _{GD}	0.2 0.2	_	_	Volts
Holding Current (V _D = 12 Vdc, Gate Open)	lН	_	30	75	mA
Gate Controlled Turn-On Time (V _D = Rated V _{DRM} , I _{TM} = 56 A Peak, I _G = 200 mA)	^t gt	_	1.5	_	μs
Critical Rate of Rise of Off-State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, T _C = 125°C)	dv/dt	_	50	_	V/µs
Critical Rate of Rise of Commutation Voltage (V _D = Rated V _{DRM} , I _{TM} = 56 A Peak, Commutating di/dt = 20.2 A/ms, Gate Unenergized, T _C = 75°C)	dv/dt(c)	_	5	_	V/µs







^{*}This device is rated for use in applications subject to high surge conditions. Care must be taken to insure proper heat sinking when the device is to be used at high sustained currents.

MAC224 Series MAC224A Series

FIGURE 3 – GATE TRIGGER CURRENT

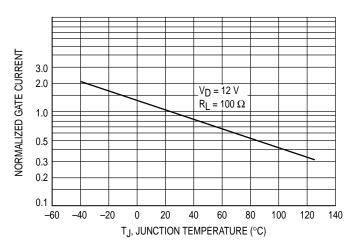


FIGURE 4 - GATE TRIGGER VOLTAGE

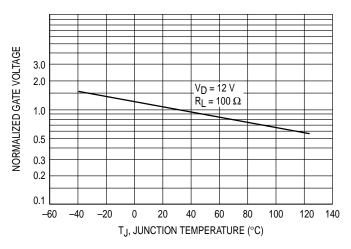


FIGURE 5 – HOLDING CURRENT

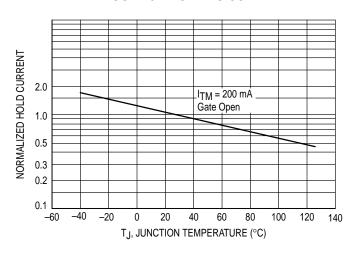


FIGURE 6 - TYPICAL ON-STATE CHARACTERISTICS

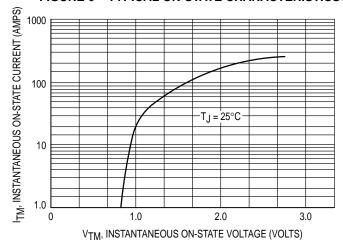
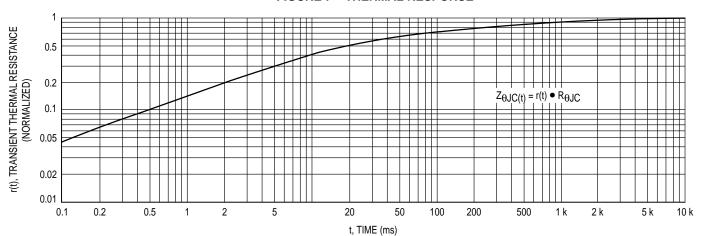
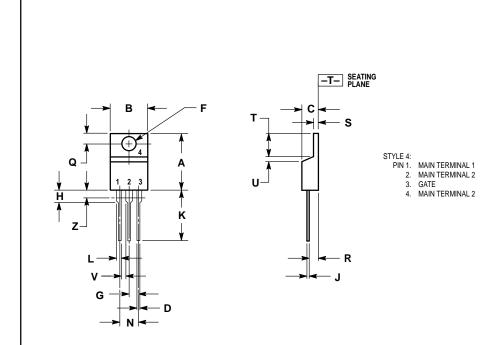


FIGURE 7 - THERMAL RESPONSE



MAC224 Series MAC224A Series

PACKAGE DIMENSIONS



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

 1. BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES MILLIMETER		IETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
7	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.055	1.15	1.39
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

CASE 221A-04 (TO-220AB)

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